Deterministic Scheme for Two-Dimensional Type-II Dirac Points and Experimental Realization in Acoustics

Xiaoxiao Wu[®], ¹ Xin Li, ² Ruo-Yang Zhang[®], ¹ Xiao Xiang, ² Jingxuan Tian, ³ Yingzhou Huang[®], ² Shuxia Wang, ² Bo Hou, ^{4,5} C. T. Chan, ¹ and Weijia Wen^{1,6,*}

¹Department of Physics, The Hong Kong University of Science and Technology,

Clear Water Bay, Kowloon, Hong Kong, China

²Chongqing Key Laboratory of Soft Condensed Matter Physics and Smart Materials, College of Physics, Chongqing University, Chongqing 400044, China

³Department of Mechanical Engineering, Faculty of Engineering, The University of Hong Kong, Hong Kong, China ⁴School of Physical Science and Technology & Collaborative Innovation Center of Suzhou Nano Science and Technology, Soochow University, Suzhou 215006, China

⁵Key Laboratory of Modern Optical Technologies of Ministry of Education & Key Lab of Advanced Optical Manufacturing Technologies of Jiangsu Province, Suzhou 215006, China ⁶Materials Genome Institute, Shanghai University, Shanghai 200444, China

(Received 10 July 2019; accepted 23 January 2020; published 21 February 2020)

Low-energy electrons near Dirac/Weyl nodal points mimic massless relativistic fermions. However, as they are not constrained by Lorentz invariance, they can exhibit tipped-over type-II Dirac/Weyl cones that provide highly anisotropic physical properties and responses, creating unique possibilities. Recently, they have been observed in several quantum and classical systems. Yet, there is still no simple and deterministic strategy to realize them since their nodal points are accidental degeneracies, unlike symmetry-guaranteed type-I counterparts. Here, we propose a band-folding scheme for constructing type-II Dirac points, and we use a tight-binding analysis to unveil its generality and deterministic nature. Through realizations in acoustics, type-II Dirac points are experimentally visualized and investigated using near-field mappings. As a direct effect of tipped-over Dirac cones, strongly tilted kink states originating from their valley-Hall properties are also observed. This deterministic scheme could serve as a platform for further investigations of intriguing physics associated with various strongly Lorentz-violating nodal points.

DOI: 10.1103/PhysRevLett.124.075501

Introduction.—In condensed matters, low-energy electrons around two- or three-dimensional (2D or 3D) Dirac/ Weyl points mimic massless fermions in high-energy physics. However, since the stringent Lorentz invariance is absent in a lattice due to breaking of continuous rotational symmetry [1], their two- or three-dimensional (2D or 3D) Dirac/Weyl cones can be tilted, which is first noted in various Dirac materials such as strained graphene [2,3]. If the tilt becomes strong enough to tip over cones in a specific direction, type-II Dirac/Weyl points (DPs/WPs) arise, with nodal points, originally isolated (Fermi surface of type-I DPs/WPs), becoming contacts of electronlike and holelike Fermi pockets (type-II DPs/WPs) [4-11]. Such topological transitions of Fermi surfaces lead to highly anisotropic optical [6,10], magnetic [5,11], and electrical [7,8] properties. In fact, these topological transitions are not unique to band structures of electronic materials, and should be realizable for any type of Bloch mode. Very recently, they have been proposed in classical systems [12–21], and experimentally demonstrated [16,17,20]. However, as accidental degeneracies, 2D type-II DPs, if they exist, only emerge at hardly predictable low-symmetry points in reciprocal space, and they still lack generally applicable design strategies, not to mention more complicated 3D type-II DPs/WPs. In contrast, type-I DPs are guaranteed to exist at corners of the first Brillouin zone (FBZ) using triangular, honeycomb, or kagome lattices [22]. This property serves as a basis for further research of many (pseudo)relativistic and topological phenomena associated with type-I DPs, such as Klein tunneling [23,24], *Zitterbewegung* effects [25–27], and various topological insulators [28–37].

In this Letter, to provide 2D type-II DPs such simple and robust platforms for further research, we introduce a deterministic construction scheme based on the bandfolding mechanism [28], with its physics illustrated using general tight-binding models. A direct experimental realization in acoustics is demonstrated, in which sonic crystals comprising bow-tie shaped holes are investigated using near-field mappings. Dispersions of type-II DPs are clearly resolved, featuring deterministic contacts between electron-like and holelike Fermi pockets. Strongly tilted valley-Hall kink modes, a direct manifestation of tipped-over Dirac cones, are also observed. The experimental results achieve

quantitative agreement with theoretical and numerical predictions. Further, the deterministic scheme can be extended to more intriguing cases, and serve as a basis for systematic investigations of (pseudo)relativistic and topological phenomena of strongly Lorentz-violating nodal points.

Results.—We begin explaining our scheme from a sonic crystal as shown in Fig. 1(a). It comprises bow-tie shaped blind holes (details in insets) arranged in a rectangular lattice, drilled on an acoustic-hard plate immersed in air. Its primitive cell is denoted by the green shaded region. The first resonance of each hole is an s-orbital cavity mode, anisotropic because of the bow-tie shape [18]. Polaritonic couplings [38,39] between plane waves and these s-orbital cavity modes give rise to spoof surface acoustic wave (SSAW) modes, forming the 1st band of the sonic crystal (see Fig. S1 in the Supplemental Material [40]). Conveniently, we choose the following geometric parameters, lattice constants $a_x/2 = 12.5$ and $a_y = 16$ mm, depth of holes h = 10 mm, and bow-tie shape $l_x = 7$, $l_y = 14$, and w = 3 mm.

Then, if we deliberately consider an enlarged unit cell [orange shaded region in Fig. 1(a)] comprising two primitive cells, the 1st band will be folded back [28]. We perform full-wave simulations including viscothermal losses (see Note S15 in the Supplemental Material [40] for setup details). The obtained nominal "1st" and "2nd" bands are degenerate along the XM direction [Fig. 1(b)], since it is exactly the fold line in reciprocal space [Fig. 1(c)]. Such degeneracy could serve as a basis for constructing type-II DPs, if we can lift the degeneracy along the line except a single point. The first step is to transform enlarged unit cells into "real" primitive unit cells. We decompose enlarged unit cells into two sublattices, left holes A and right holes B [see inset in Fig. 1(b)], and locally rotate left holes (sublattice A) with 90° [Fig. 1(d)]. Subsequently, the band structure [Fig. 1(e)] shows that 1st and 2nd bands now only touch linearly at the midpoint $D(\pi/a_x, \pi/(2a_y))$ of the XM direction, where a type-II DP emerges at frequency $f_D = 6.39$ kHz, as highlighted by the green-dashed rectangle. Because of time-reversal symmetry, they will also touch at another inequivalent point $D'(\pi/a_x, -\pi/(2a_y))$, and inset in Fig. 1(e) summarizes their distribution. The 3D band structure around the D point [Fig. 1(f)] visualizes with great detail the point touch between the two bands. Field maps at the D point [Figs. 1(g) and 1(h)] reveal that the degenerate doublets, with pressure localized in different sublattices, exhibit opposite parities with respect to the mirror symmetry Σ_A (yellow dashed lines), ensuring their orthogonality. Thus, the symmetric (antisymmetric) eigenmode belongs to the A_1 (A_2) representation of the C_{2v} point group, and the type-II DPs only correspond to accidental degeneracies. However, the emergence and distribution of the type-II DPs are indeed insensitive to shapes and geometric parameters of the mirror-symmetric holes (see Fig. S2 in the Supplemental Material [40] for further

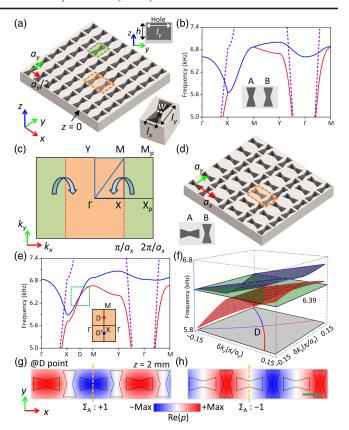


FIG. 1. Band-folding creation of type-II DPs. (a) Initial sonic crystal, an acoustic-hard plate with bow-tie shaped blind holes arranged in a rectangular lattice. Green (orange) shaded region denotes a primitive (enlarged) unit cell. Perspective view of primitive cell in bottom-right inset, sectional side view in topright inset. (b) Calculated band structure of (a) using enlarged unit cells depicted in inset, comprising sublattices A and B. Dashed lines: sound cone. (c) Folding mechanism of the first Brillouin zone when considering enlarged unit cells. Outer green region (XX_PM_PM) of the original FBZ are folded back into the inner orange region (ΓXMY) along the fold line (XM). (d) Rotation (90°) of left holes (sublattice A) in enlarged unit cells transform them into real unit cells (orange shaded region). Inset: schematic of transformed unit cell. (e) Band structure of sonic crystal in (d). The 1st (red) and 2nd (blue) bands linearly touch each other in midpoint D of the XM direction, highlighted by the green dashed rectangle. Inset: distribution of type-II DPs in the Brillouin zone. Because of time-reversal symmetry, another inequivalent type-II DP exists at D'. (f) 3D band structure around the D point. At Dirac frequency 6.39 kHz (green, semi-transparent plane) of the type-II DP, its iso-frequency contour features a pair of crossing lines contacting at D. (g),(h) Pressure fields of degenerate doublets at D, corresponding to eigenvalues ± 1 of mirror symmetry Σ_A indicated by orange dashed lines. Green scale bar: 10 mm.

examples, and Note S1 for preference of bow-tie shapes). In addition, the physics of type-II DPs is not affected by viscothermal losses in the sonic crystal, which only slightly shift frequencies of its bands (see Fig. S11 for discussion [40]).

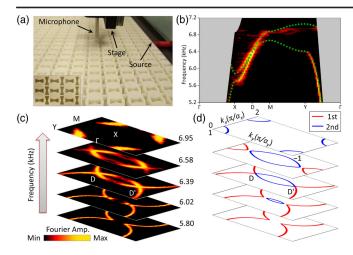


FIG. 2. Experimental imaging of type-II DPs. (a) Photograph of experimental setup for near-field mappings (see note S15 in the Supplemental Material for details [40]). Inset: close top view of the 3D printed sample. (b) Fourier spectra along high-symmetry directions of FBZ. Green dots indicate numerical dispersion. Only regions outside the sound cone are shown. (c) Fourier spectra at selected frequencies. Bright strips represent excited SSAW modes, indicating their IFCs in reciprocal space. (d) Numerically calculated IFCs at corresponding frequencies. Type-II DPs manifest themselves as the contacts of "electronlike" (red IFCs) and "holelike" (blue IFCs) Fermi pockets. Note that a Brillouin zone is topologically equivalent to a torus [43].

Before investigating the mechanism, we first perform near-field mappings with 3D-printed samples to confirm our findings [experiment setup in Fig. 2(a), see Note S15 in Ref. [40] for details). From Fourier transforms of mapped pressure fields, the Fourier spectra along highsymmetry directions in reciprocal space are retrieved [Fig. 2(b)]. Bright strips signify the SSAW modes excited in experiments [41,42], whose dispersions agree excellently with the simulated one (green dots). Further, Fourier spectra in the whole Brillouin zone are stacked with increasing frequency [Fig. 2(c)], where bright strips indicate iso-frequency contours (IFCs) of the sonic crystal. Numerically calculated IFCs at corresponding frequencies are plotted for reference [Fig. 2(d)], and their evolutions agree quite well: when frequency increases, the number of closed IFCs, that is, Fermi pockets [1], changes from 1 to 2, and finally to 1 again. Amidst this transition, type-II DPs emerge as the contacts between the "electronlike" (1st band) and "holelike" (2nd band) Fermi pockets [9,14,16,18].

To analytically investigate the mechanism, we employ a tight-binding model [Fig. 3(a)] since s-orbital SSAW modes are well localized. We first only consider nearest-neighbor (NN) hoppings, including the x direction t_x , and the y direction t_{yA} and t_{yB} . From Fourier transforms on tight-binding Hamiltonians in real space (see Note S15 [40]), we obtain Hamiltonian $H(\mathbf{k})$ in reciprocal space,

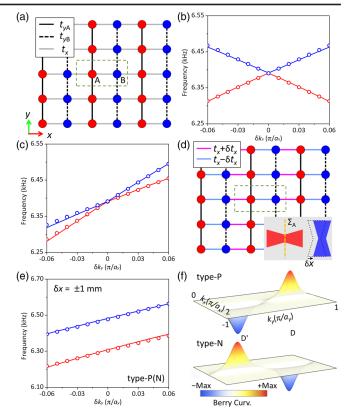


FIG. 3. Tight-binding analysis of band-folding mechanism. (a) Tight-binding model of sonic crystal in Fig. 1(d). The s-orbital SSAW modes in sublattice A (B) are represented by red (blue) lattice points. Only nearest-neighbor hoppings are considered. (b), (c) Band structure near the D point along the x direction (b) or y direction (c), calculated from simulations (sold lines) or the tightbinding model (scatters) in (a). (d) The tight-binding model when sublattice B is shifted with displacement $\delta \mathbf{r} = (\delta x, 0)$, which breaks mirror symmetry Σ_A and creates hopping difference δt_x along the x direction. Inset: detailed schematic of displacement. (e) Band structure near the D point along the y direction for type-P $(\delta x = +1 \text{ mm})$ and type-N $(\delta x = -1 \text{ mm})$ unit cells, calculated from simulations (sold lines) or tight-binding model (scatters) in (d). (f) Berry curvature distributions for type-P and type-N unit cells, calculated from the tight-binding model in (d) (see Fig. S6 and Note S8 in the Supplemental Material [40]).

$$H(\mathbf{k}) = \begin{bmatrix} \omega_0 - t_{yA} (e^{ik_y a_y} + e^{-ik_y a_y}) & -t_x (1 + e^{ik_x a_x}) \\ -t_x (1 + e^{-ik_x a_x}) & \omega_0 - t_{yB} (e^{ik_y a_y} + e^{-ik_y a_y}) \end{bmatrix},$$

$$(1)$$

where ω_0 is the on-site angular frequency of both sublattices, and $\mathbf{k} = (k_x, k_y)$ is the Bloch wave vector. Around the midpoint $D(\pi/a_x, \pi/(2a_y))$ of the *XM* direction, we expand $H(\mathbf{k})$ with respect to the deviation $\delta \mathbf{k} = (\delta k_x, \delta k_y)$. To the first order, we have (see Note S2 for details [40])

$$H(D + \delta \mathbf{k}) = t_{ys} a_y \delta k_y \sigma_0 - t_x a_x \delta k_x \sigma_2 - t_{yd} a_y \delta k_y \sigma_3 + \omega_0 \sigma_0,$$
(2)

where σ_0 is the identity matrix and σ_i (i=1, 2, 3) are Pauli matrices, with parameters $t_{ys} = t_{yA} + t_{yB}$ and $t_{yd} = t_{yB} - t_{yA}$. The Taylor-expanded Hamiltonian in Eq. (2) is identical to Hamiltonians of type-II DPs obtained from the lowest-order $\mathbf{k} \cdot \mathbf{p}$ method in previous works [9,14,16] up to unitary transformations. Because of the first tilt term, the Dirac cone at the *D* point is tipped over towards the +y direction, and since $|t_{ys}| > |t_{yd}|$, the tilt term dominates, resulting in a type-II DP [16,44]. To confirm this picture, we calculate (angular) eigenfrequencies from Eq. (2),

$$\omega_{\pm}(D+\delta\mathbf{k}) = \omega_0 + v_{ys}\delta k_y \pm \sqrt{(v_x \delta k_x)^2 + (v_{yd}\delta k_y)^2}, \quad (3)$$

where the sign + (-) denotes the 2nd (1st) band, and parameters $v_x = t_x a_x$, $v_{ys} = t_{ys} a_y$, and $v_{yd} = t_{yd} a_y$ characterize anisotropic group velocities (see Note S15 for fitting of parameters [40]). As established in Eq. (3), which agrees well with numerical dispersions [Figs. 3(b) and 3(c)], the type-II DP is fixed at both a deterministic location (D point) and frequency (ω_0). The conclusion, due to collaboration of mirror symmetry and identical onsite frequencies, is still valid after taking into account next-nearest-neighbor hoppings (see Notes S4 and S5 in the Supplemental Material [40]).

To ensure this simple model has captured the essence of the deterministic scheme, we consider another sonic crystal comprising coupled resonant cavities [34]. Under similar perturbations, it also realizes type-II DPs (see Note S3 and Fig. S3 in Ref. [40]). Therefore, when a mirror-symmetric rectangular (or square) lattice is folded along the mirror direction, a strong tilt naturally arises in its band structure on the corresponding FBZ boundary. Then, a pair of mirror-symmetry protected type-II DPs deterministically emerge around midpoints of the FBZ boundary once we detune NN hoppings in each sublattice along the "unfolded" direction (see argument on its deterministic nature [45] in Note S13 [40]).

For further corroboration of the scheme, we examine a direct effect of tipped-over Dirac cones: valley-Hall kink states (VHKSs), induced by localized Berry curvatures of gapped type-II DPs, are so strongly tilted that they propagate along the same direction at each "valley" when hosted in opposite supercells. They may be termed type-II VHKSs to distinguish from type-I VHKSs induced by gapped type-I DPs [29,32,46,47], which propagate along opposite directions when hosted in opposite supercells. To create type-II VHKSs, we first introduce perturbations breaking mirror symmetry Σ_A which protects type-II DPs. Simply, we shift sublattice B with displacement $\delta \mathbf{r} = (\delta x, 0)$, which introduces hopping difference δt_x in the x direction [Fig. 3(d)], resulting in a mass term (see Note S6 [40]). We label a unit cell as type-P (type-N) if $\delta x > 0$ ($\delta x < 0$). Two opposite shifts $\delta \mathbf{r} = (\pm \delta x, 0)$ lead to identical band structures but opposite valley-Hall properties. Without loss of generality, we focus on representing cases $\delta x = \pm 1$ mm. Again, the tight-binding model correctly depicts band structure around the D point [Fig. 3(e)], featuring a partial band gap (see also Fig. S4 in Ref. [40]). Then, we calculate their 1st-band Berry curvatures $\Omega_{z,-}$ using a tight-binding Hamiltonian including hopping difference δt_x (see Note S8 [40]) [48–52]. Anisotropic peaks emerge around the D/D' point [Fig. 3(f)], and they can be approximated as (see Note S8 [40])

$$\Omega_{zD/D',-}(\delta \mathbf{k}) = \pm \frac{v_x v_{yd} \Delta_p}{2[(v_x \delta k_x)^2 + (v_{yd} \delta k_y)^2 + \Delta_p^2]^{3/2}}, \quad (4)$$

where $\Delta_p = 2\delta t_x$, and the sign + (-) corresponds to the D (D') point. Since the Berry curvatures are localized, it is possible to define half-quantized valley-Chern numbers [16,29,46] around the D/D' point on half of the FBZ (HFBZ)

$$C_{V,-}^{D/D'} = \frac{1}{2\pi} \int_{\text{HFB7}} \Omega_{zD/D',-} d^2 \mathbf{k} = \pm \frac{1}{2} \text{sgn}(v_{yd} \Delta_p),$$
 (5)

which is +1/2 (-1/2) for type-P (type-N) at the D point, and reversed at the D' point (see Note S8 [40]). For type-II VHKSs, positive (negative) differences of valley-Chern numbers indicate faster (slower) propagations, instead of forward (backward) propagations for type-I VHKSs [29,46] (see Note S9 [40] for derivations).

We then construct two possible supercells comprising a kink running along the y direction, which we refer to as the PN-configuration [Fig. 4(a)] and the NP-configuration [Fig. 4(b)]. The NP-configuration is mirror (Σ_A) opposite of the PN-configuration, and they cannot be transformed into each other through SO(3) operations. As shown in their projected band structures [Fig. 4(c)], strongly tilted type-II VHKSs emerge in the partial band gap, and their pressure fields [Figs. 4(d) and 4(e)] both demonstrate exponential decay profiles in bulk domains (see Fig. S7 for precise distributions [40]). They can give rise to time-reversal symmetric counterparts of antichiral edge states (see Note S14 [40]) [33,53]. They also exhibit sublattice polarizations with their pressure fields almost exclusively localized in sublattice A or B (see Note S9 [40] for derivations). Besides, it is found that there are no kink states for interfaces along the x direction (see Fig. S12 [40]).

Last, we perform near-field mappings to detect type-II VHKSs. Spatial Fourier spectra [Figs. 4(f) and 4(g)], averaged over $\pm k_y$, are retrieved from imaged pressure fields. They correspond to the PN-configuration and NP-configuration samples, respectively, both stimulated with matched sublattice polarizations (see Note S15 [40] for details). In the spectra, bright narrow strips clearly demonstrate successfully excited type-II VHKSs and they agree quantitatively with numerically calculated dispersions

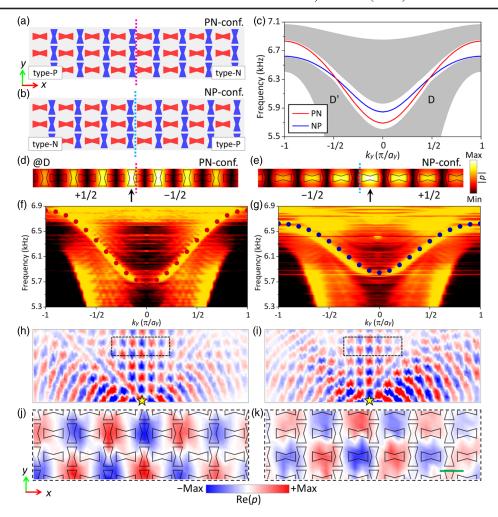


FIG. 4. Observation of type-II valley-Hall kink states (VHKSs). (a),(b) Schematics of supercells periodic along the y direction, formed by type-P and type-N unit cells, referred to as the PN-configuration (a) and NP-configuration (b), respectively. Dashed lines indicate kinks between two domains. (c) Numerically calculated projected band structure. Gray shaded regions correspond to bulk bands. Type-II VHKS of the PN-configuration (NP-configuration) is denoted by red (blue) solid line. (d),(e) Simulated pressure fields of type-II VHKSs at the projected D point ($k_y = \pi/(2a_y)$), for the PN-configuration (d) and NP-configuration (e), respectively. Black arrows indicate where pressure is the strongest. (f),(g) Fourier spectra obtained from measured pressure field maps for the PN-configuration (f) and NP-configuration (g), excited with matched sublattice polarizations. Dark red (blue) dots indicate numerical dispersion of type-II VHKSs in the PN-configuration (NP-configuration). (h), (i) Experimentally imaged pressure fields at 6.40 kHz for the PN-configuration (h) and NP-configuration (i). Yellow stars indicate where source sounds are injected. (j),(k) Enlarged views of selected areas enclosed by black dashed rectangles in (h),(i), revealing sublattice polarizations of type-II VHKSs in the PN-configuration (j) and NP-configuration (k). Green scale bar: 16 mm.

(dark red and blue dots). To visualize the excited states, we plot imaged field maps at 6.40 kHz (see Fig. S8 in the Supplemental Material [40] for other frequencies) for the PN-configuration (NP-configuration) sample in Fig. 4(h) [Fig. 4(i)]. It is seen that type-II VHKSs in both samples propagate along the +y direction, alongside bulk states spreading laterally (see their time-harmonic animations in movies S1 and S2 in the Supplemental Material [40]). Moreover, pressure fields of type-II VHKSs in the PN-configuration (NP-configuration) sample are largely localized in sublattice B(A), as displayed in their enlarged views [Figs. 4(j) and 4(k)], agreeing with predicted sublattice polarizations. When the samples are stimulated with

mismatched sublattice polarizations, type-II VHKSs are much more weakly excited (see Fig. S9 and movies S3 and S4 in the Supplemental Material [40]). For comparison, we have also imaged fields of a reference sample comprising only type-*N* unit cells, and only bulk bands are observed in both real and reciprocal spaces (see Fig. S10 and movies S5 and S6 in Ref. [40]).

Finally, we note that our scheme can be directly extended to deterministically realize other strongly Lorentz-violating nodal points. For example, 3D type-II DPs [54,55] are realized by alternating stacking of coupled resonant cavities and their sublattice-polarized surface-arc states are demonstrated (see Note S10 [40]), while 2D type-III DPs

(Fermi surface critically tilted, turning into a line) [56] are realized by eliminating NN hoppings in one sublattice (see Note S11 [40]). Until now, most classical strongly Lorentz-violating nodal points are only realized in photonics [16,56,57], but they usually employ polarization as a key degree of freedom, which is intrinsically absent in sound, a scalar field. Our deterministic schemes thus provide general recipes for realizing them in scalar waves lacking any internal degrees of freedom.

Discussion.—In summary, we propose and experimentally confirm a deterministic scheme for type-II DPs based on the band-folding mechanism. Realized in acoustics, the scheme is further understood through a general tightbinding model, and has potential to inspire construction of type-II DPs in other research areas, such as electronic materials and coupled photonic waveguides. The scheme can be extended to deterministically realize other strongly Lorentz-violating nodal points, such as 3D type-II DPs and 2D type-III DPs (see notes S10 and S11 [40]). With an additional parameter, the scheme also leads to type-II synthetic WPs (see note S12 [40]). If more parameters are introduced, it could enable constructions of peculiar topological defects occurring at higher synthetic dimensions. The deterministic scheme could serve as a versatile platform for further investigations on topological phenomena, such as Klein tunneling [23,24], Zitterbewegung effects [25-27], synthetic Landau levels [35], and non-Hermitian physics [31], in the context of strongly Lorentzviolating nodal points, which may lead to exotic properties.

The authors gratefully acknowledge anonymous referees for their constructive comments and suggestions. The work is supported by Hong Kong Research Grants Council (RGC) grants (AoE/P-02/12, 16304717, and 16204019), the National Natural Science Foundation of China (11974067), Fundamental Research Funds for the Central Universities (2019CDYGYB017), and Natural Science Foundation Project of CQ CSTC (cstc2019jcyj-msxmX0145).

- *To whom all correspondence should be addressed. phwen@ust.hk
- [1] A. A. Soluyanov, D. Gresch, Z. Wang, Q. Wu, M. Troyer, X. Dai, and B. A. Bernevig, Type-II weyl semimetals, Nature (London) **527**, 495 (2015).
- [2] M. Goerbig, J.-N. Fuchs, G. Montambaux, and F. Piéchon, Tilted anisotropic Dirac cones in quinoid-type graphene and α-(BEDT – TTF)₂I₃, Phys. Rev. B 78, 045415 (2008).
- [3] M. Trescher, B. Sbierski, P. W. Brouwer, and E. J. Bergholtz, Quantum transport in Dirac materials: Signatures of tilted and anisotropic Dirac and Weyl cones, Phys. Rev. B **91**, 115135 (2015)
- [4] L. Huang, T. M. McCormick, M. Ochi, Z. Zhao, M.-T. Suzuki, R. Arita, Y. Wu, D. Mou, H. Cao, and J. Yan, Spectroscopic evidence for a type II Weyl semimetallic state in MoTe₂, Nat. Mater. 15, 1155 (2016).

- [5] T. O'Brien, M. Diez, and C. Beenakker, Magnetic Breakdown and Klein Tunneling in a Type-II Weyl Semimetal, Phys. Rev. Lett. 116, 236401 (2016).
- [6] A. Frenzel, C. Homes, Q. Gibson, Y. Shao, K. Post, A. Charnukha, R. J. Cava, and D. Basov, Anisotropic electro-dynamics of type-II Weyl semimetal candidate WTe₂, Phys. Rev. B 95, 245140 (2017).
- [7] N. Kumar, Y. Sun, N. Xu, K. Manna, M. Yao, V. Süss, I. Leermakers, O. Young, T. Förster, and M. Schmidt, Extremely high magnetoresistance and conductivity in the type-II Weyl semimetals WP₂ and MoP₂, Nat. Commun. 8, 1642 (2017).
- [8] F. Fei, X. Bo, R. Wang, B. Wu, J. Jiang, D. Fu, M. Gao, H. Zheng, Y. Chen, and X. Wang, Nontrivial Berry phase and type-II Dirac transport in the layered material PdTe₂, Phys. Rev. B 96, 041201 (2017).
- [9] M. Horio, C. Matt, K. Kramer, D. Sutter, A. Cook, Y. Sassa, K. Hauser, M. Månsson, N. Plumb, and M. Shi, Twodimensional type-II Dirac fermions in layered oxides, Nat. Commun. 9, 3252 (2018).
- [10] J. Lai, X. Liu, J. Ma, Q. Wang, K. Zhang, X. Ren, Y. Liu, Q. Gu, X. Zhuo, and W. Lu, Anisotropic broadband photo-response of layered type-II weyl semimetal MoTe₂, Adv. Mater. 30, 1707152 (2018).
- [11] K.-W. Chen, X. Lian, Y. Lai, N. Aryal, Y.-C. Chiu, W. Lan, D. Graf, E. Manousakis, R. Baumbach, and L. Balicas, Bulk Fermi Surfaces of the Dirac Type-II Semimetallic Candidates M Al₃ (Where *M* = *V*, Nb, and Ta), Phys. Rev. Lett. **120**, 206401 (2018).
- [12] Z. Yang and B. Zhang, Acoustic Type-II Weyl Nodes from Stacking Dimerized Chains, Phys. Rev. Lett. **117**, 224301 (2016).
- [13] H.-X. Wang, Y. Chen, Z. H. Hang, H.-Y. Kee, and J.-H. Jiang, Type-II Dirac photons, Quantum Mater. 2, 54 (2017)
- [14] G. G. Pyrialakos, N. S. Nye, N. V. Kantartzis, and D. N. Christodoulides, Emergence of Type-II Dirac Points in Graphynelike Photonic Lattices, Phys. Rev. Lett. 119, 113901 (2017).
- [15] C.-R. Mann, T. J. Sturges, G. Weick, W. L. Barnes, and E. Mariani, Manipulating type-I and type-II Dirac polaritons in cavity-embedded honeycomb metasurfaces, Nat. Commun. 9, 2194 (2018).
- [16] C. Hu, Z. Li, R. Tong, X. Wu, Z. Xia, L. Wang, S. Li, Y. Huang, S. Wang, B. Hou, C. T. Chan, and W. Wen, Type-II Dirac Photons at Metasurfaces, Phys. Rev. Lett. 121, 024301 (2018).
- [17] J. Noh, S. Huang, D. Leykam, Y. D. Chong, K. P. Chen, and M. C. Rechtsman, Experimental observation of optical Weyl points and Fermi arc-like surface states, Nat. Phys. 13, 611 (2017).
- [18] J. Y. Lin, N. C. Hu, Y. J. Chen, C. H. Lee, and X. Zhang, Line nodes, Dirac points, and Lifshitz transition in twodimensional nonsymmorphic photonic crystals, Phys. Rev. B 96, 075438 (2017).
- [19] Q. Guo, B. Yang, L. Xia, W. Gao, H. Liu, J. Chen, Y. Xiang, and S. Zhang, Three Dimensional Photonic Dirac Points in Metamaterials, Phys. Rev. Lett. 119, 213901 (2017).
- [20] B. Xie, H. Liu, H. Cheng, Z. Liu, S. Chen, and J. Tian, Experimental Realization of Type-II Weyl Points and Fermi

- Arcs in Phononic Crystal, Phys. Rev. Lett. **122**, 104302 (2019).
- [21] Z. Liu, Q. Zhang, F. Qin, D. Zhang, X. Liu, and J. J. Xiao, Type-II Dirac point and extreme dispersion in one-dimensional plasmonic-dielectric crystals with off-axis propagation, Phys. Rev. A 99, 043828 (2019).
- [22] T. Ozawa, H. M. Price, A. Amo, N. Goldman, M. Hafezi, L. Lu, M. Rechtsman, D. Schuster, J. Simon, and O. Zilberberg, Topological photonics, Rev. Mod. Phys. 91, 015006 (2019).
- [23] O. Bahat-Treidel, O. Peleg, M. Grobman, N. Shapira, M. Segev, and T. Pereg-Barnea, Klein Tunneling in Deformed Honeycomb Lattices, Phys. Rev. Lett. 104, 063901 (2010).
- [24] X. Ni, D. Purtseladze, D. A. Smirnova, A. Slobozhanyuk, A. Alù, and A. B. Khanikaev, Spin-and valley-polarized one-way Klein tunneling in photonic topological insulators, Sci. Adv. 4, eaap8802 (2018).
- [25] X. Zhang, Observing Zitterbewegung for Photons near the Dirac Point of a Two-Dimensional Photonic Crystal, Phys. Rev. Lett. 100, 113903 (2008).
- [26] F. Dreisow, M. Heinrich, R. Keil, A. Tünnermann, S. Nolte, S. Longhi, and A. Szameit, Classical Simulation of Relativistic Zitterbewegung in Photonic Lattices, Phys. Rev. Lett. 105, 143902 (2010).
- [27] W. Ye, Y. Liu, J. Liu, S. A. Horsley, S. Wen, and S. Zhang, Photonic Hall effect and helical Zitterbewegung in a synthetic Weyl system, Light Sci. Appl. **8**, 49 (2019).
- [28] L.-H. Wu and X. Hu, Scheme for Achieving a Topological Photonic Crystal by Using Dielectric Material, Phys. Rev. Lett. 114, 223901 (2015).
- [29] X. Wu, Y. Meng, J. Tian, Y. Huang, H. Xiang, D. Han, and W. Wen, Direct observation of valley-polarized topological edge states in designer surface plasmon crystals, Nat. Commun. 8, 1304 (2017).
- [30] Z. Zhang, Q. Wei, Y. Cheng, T. Zhang, D. Wu, and X. Liu, Topological Creation of Acoustic Pseudospin Multipoles in a Flow-Free Symmetry-Broken Metamaterial Lattice, Phys. Rev. Lett. 118, 084303 (2017).
- [31] M. Wang, L. Ye, J. Christensen, and Z. Liu, Valley Physics in Non-Hermitian Artificial Acoustic Boron Nitride, Phys. Rev. Lett. **120**, 246601 (2018).
- [32] J. Noh, S. Huang, K. P. Chen, and M. C. Rechtsman, Observation of Photonic Topological Valley Hall Edge States, Phys. Rev. Lett. **120**, 063902 (2018).
- [33] E. Colomés and M. Franz, Antichiral Edge States in a Modified Haldane Nanoribbon, Phys. Rev. Lett. 120, 086603 (2018).
- [34] X. Ni, M. Weiner, A. Alù, and A. B. Khanikaev, Observation of higher-order topological acoustic states protected by generalized chiral symmetry, Nat. Mater. 18, 113 (2019).
- [35] X. Wen, C. Qiu, Y. Qi, L. Ye, M. Ke, F. Zhang, and Z. Liu, Acoustic Landau quantization and quantum-Hall-like edge states, Nat. Phys. **15**, 352 (2019).
- [36] Z. Zhu, X. Huang, J. Lu, M. Yan, F. Li, W. Deng, and Z. Liu, Negative Refraction and Partition in Acoustic Valley Materials of a Square Lattice, Phys. Rev. Applied 12, 024007 (2019).
- [37] B. Xie, H. Liu, H. Cheng, Z. Liu, S. Chen, and J. Tian, Acoustic Topological Transport and Refraction in a Kekulé Lattice, Phys. Rev. Applied 11, 044086 (2019).

- [38] D. Torrent and J. Sánchez-Dehesa, Acoustic Analogue of Graphene: Observation of Dirac Cones in Acoustic Surface Waves, Phys. Rev. Lett. 108, 174301 (2012).
- [39] S. Yves, R. Fleury, F. Lemoult, M. Fink, and G. Lerosey, Topological acoustic polaritons: Robust sound manipulation at the subwavelength scale, New J. Phys. 19, 075003 (2017).
- [40] See Supplemental Material at http://link.aps.org/supplemental/ 10.1103/PhysRevLett.124.075501 for more details, featuring design details of the sonic crystal, effective Hamiltonian analysis, topology of gapped type-II DPs, analytical solutions of kink states and their experimentally imaged time-harmonic animations, deterministic schemes of other strongly Lorentzviolating nodal points, time-reversal symmetric counterpart of antichiral edge states, and methods in calculations, simulations, and experiments.
- [41] J. Lu, C. Qiu, L. Ye, X. Fan, M. Ke, F. Zhang, and Z. Liu, Observation of topological valley transport of sound in sonic crystals, Nat. Phys. 13, 369 (2017).
- [42] F. Li, X. Huang, J. Lu, J. Ma, and Z. Liu, Weyl points and Fermi arcs in a chiral phononic crystal, Nat. Phys. **14**, 30 (2018).
- [43] L. Lu, J. D. Joannopoulos, and M. Soljačić, Topological photonics, Nat. Photonics 8, 821 (2014).
- [44] S. Li, Z.-M. Yu, Y. Liu, S. Guan, S.-S. Wang, X. Zhang, Y. Yao, and S. A. Yang, Type-II nodal loops: Theory and material realization, Phys. Rev. B **96**, 081106(R) (2017).
- [45] K. Asano and C. Hotta, Designing Dirac points in two-dimensional lattices, Phys. Rev. B 83, 245125 (2011).
- [46] F. Gao, H. Xue, Z. Yang, K. Lai, Y. Yu, X. Lin, Y. Chong, G. Shvets, and B. Zhang, Topologically protected refraction of robust kink states in valley photonic crystals, Nat. Phys. 14, 140 (2018).
- [47] L. Ju, Z. Shi, N. Nair, Y. Lv, C. Jin, J. Velasco Jr, C. Ojeda-Aristizabal, H. A. Bechtel, M. C. Martin, and A. Zettl, Topological valley transport at bilayer graphene domain walls, Nature (London) **520**, 650 (2015).
- [48] J. Mei, Y. Wu, C. Chan, and Z.-Q. Zhang, First-principles study of Dirac and Dirac-like cones in phononic and photonic crystals, Phys. Rev. B **86**, 035141 (2012).
- [49] J. Jung, F. Zhang, Z. Qiao, and A. H. MacDonald, Valley-Hall kink and edge states in multilayer graphene, Phys. Rev. B 84, 075418 (2011).
- [50] M. Fruchart, D. Carpentier, and K. Gawędzki, Parallel transport and band theory in crystals, Europhys. Lett. **106**, 60002 (2014).
- [51] E. Dobardžić, M. Dimitrijević, and M. Milovanović, Generalized Bloch theorem and topological characterization, Phys. Rev. B **91**, 125424 (2015).
- [52] G. Tkachov, Topological Insulators: The Physics of Spin Helicity in Quantum Transport (CRC Press, Boca Raton, 2015).
- [53] S. Mandal, R. Ge, and T. C. H. Liew, Antichiral edge states in an exciton polariton strip, Phys. Rev. B **99**, 115423 (2019).
- [54] H. Wang, L. Xu, H. Chen, and J.-H. Jiang, Three-dimensional photonic Dirac points stabilized by point group symmetry, Phys. Rev. B **93**, 235155 (2016).
- [55] T.-R. Chang, S.-Y. Xu, D. S. Sanchez, W.-F. Tsai, S.-M. Huang, G. Chang, C.-H. Hsu, G. Bian, I. Belopolski, and Z.-M. Yu, Type-II Symmetry-Protected Topological Dirac Semimetals, Phys. Rev. Lett. 119, 026404 (2017).

- [56] M. Milićević, G. Montambaux, T. Ozawa, O. Jamadi, B. Real, I. Sagnes, A. Lemaître, L. Le Gratiet, A. Harouri, and J. Bloch, Type-III and Tilted Dirac Cones Emerging from Flat Bands in Photonic Orbital Graphene, Phys. Rev. X 9, 031010 (2019).
- [57] Q. Guo, O. You, B. Yang, J. B. Sellman, E. Blythe, H. Liu, Y. Xiang, J. Li, D. Fan, and J. Chen, Observation of Three-Dimensional Photonic Dirac Points and Spin-Polarized Surface Arcs, Phys. Rev. Lett. 122, 203903 (2019).